5. (Amended) A self-light emitting display device comprising:

a first electrode formed on an insulator;

an EL layer formed on the first electrode;

a second electrode formed on the EL layer; and

a light scattering body formed at a side opposite to the first electrode through the insulator.

26. (Amended) A self-light emitting display device comprising:

a first electrode formed on an insulator;

an EL layer formed on the first electrode;

a second electrode formed on the EL layer; and

a light scattering body formed on the surface facing a material with the lowest refractive index.

37. (Amended) A self-light emitting display device comprising:

a substrate;

a first electrode formed over a first surface of the substrate;

an EL layer formed on the first electrode;

a second electrode formed on the EL layer; and

a light scattering body formed over a second surface of the substrate which is opposite to the first surface.

43. (Amended) A self-light emitting device according to claim 37, wherein a thickness (H)

of the light scattering body has a relation of H ≧ W1 with respect to a pitch (W1) of the light scattering body.

47. (Amended) A self-light emitting display device comprising:

a substrate;

a first electrode formed over a first surface of the substrate;

an EL layer formed on the first electrode;

a second electrode formed on the EL layer; and

a light scattering body formed over a second surface of the substrate which is opposite to the first surface,

wherein a thickness (H) of the light scattering body has a relation of H ≧ W1 with respect to a pitch (W1) of the light scattering body.

56. (Amended) A self-light emitting display device comprising:

a substrate;

a first electrode formed over a first surface of the substrate;

an EL layer formed on the first electrode;

a second electrode formed on the EL layer; and

a light scattering body formed over a second surface of the substrate which is opposite to the first surface,

wherein an angle between the light scattering body and the second surface is not less than 60°and is less than 180°.

62. (Amended) A self-light emitting device according to claim 56, wherein a thickness (H) of the light scattering body has a relation of H ≧ W1 with respect to a pitch (W1) of the light scattering body.

65. (Amended) A self-light emitting display device comprising:

a substrate;

a first electrode formed over a first surface of the substrate;

an EL layer formed on the first electrode;

a second electrode formed on the EL layer; and

a light scattering body formed over the second electrode.

69. (Amended) A self-light emitting device according to claim 65, wherein a thickness (H) of the light scattering body has a relation of H ≧ W1 with respect to a pitch (W1) of the light scattering body.

Please add the following new claims:

73. (New) A self-light emitting display device comprising:

a substrate having a first surface and a second surface opposite to each other;

a plurality of light emitting elements arranged in a matrix form over the first surface of the substrate; and

a light scattering body adjacent the second surface of the substrate.

74. (New) A self-light emitting display device comprising:

a substrate having a first surface and a second surface opposite to each other;

a passivation film formed over the plurality of light emitting elements;

a sealing film formed over the passivation film;

a sealing substrate formed over the sealing film; and

a light scattering body formed over the sealing substrate.

75. (New) A self-light emitting display device comprising:

a substrate having a first surface and a second surface opposite to each other;

a passivation film formed over the plurality of light emitting elements;

a light scattering body formed over the passivation film.

76. (New) The self-light emitting display device according to claim 74, wherein the passivation film comprises at least one of silicon nitride and carbon film.

77. (New) The self-light emitting display device according to claim 75, wherein the passivation film comprises at least one of silicon nitride and carbon film.